
Learn how to find a substitute transistor by analyzing voltage, current and package compatibility. HY1906P MOSFET PDF Datasheet: N-Ch/60V/120A. View the complete specification, pin ...

Description: N-Channel Enhancement Mode MOSFET. Manufacturer: HUAYI MICROELECTRONICS CO.,LTD..

Part Name Description Manufacturer HY1906 N-Channel Enhancement Mode MOSFET / TO-220 Package Unspecified 1 2 3 4 5 6 7 8 9 10 HY1906P N-Channel Enhancement Mode MOSFET ...

Learn how to find a substitute transistor by analyzing voltage, current and package compatibility. HY1906P MOSFET PDF Datasheet: N ...

Description: Single N-Channel Enhancement Mode MOSFET. 8 Results. Datasheet: 598Kb/11P. Manufacturer: HUAYI MICROELECTRONICS CO.,LTD..

Power Control: The high-quality FET inverter transistor HY1906 is designed for efficient power control and switching in high-power circuits. Thermal Management: Equipped with a TO-220 ...

Key features, pinout, electrical characteristics, block diagram, and application circuit for n-channel enhancement mode mosfet.

Description: N-Channel Enhancement Mode MOSFET. Manufacturer: ...

This IC is commonly used in power management applications, specifically as a synchronous step-down converter. Understanding the information contained within the Hy1906 ...

Power Management for Inverter Systems. Absolute Maximum Ratings 1. Drain-Source Voltage : Vdss = 60 V 2. Gate-Source Voltage : Vgss = ±25 V 3. Diode Continuous Forward Current : Is ...

HY1906 Datasheet - 60V, 120A, N-Channel MOSFET Posted on July 2, 2022 by pinout

Power Management for Inverter Systems. Note: HUAYI lead-free products contain molding compounds/die attach materials and 100% matte tin plate Termin ation finish;which are fully ...

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